

UT54ACS365/UT54ACTS365

Radiation-Hardened

Hex Buffers/Line Drivers with Three-State Outputs

FEATURES

- 1.2 μ radiation-hardened CMOS
 - Latchup immune
- High speed
- Low power consumption
- Single 5 volt supply
- Available QML Q or V processes
- Flexible package
 - 16-pin DIP
 - 16-lead flatpack

DESCRIPTION

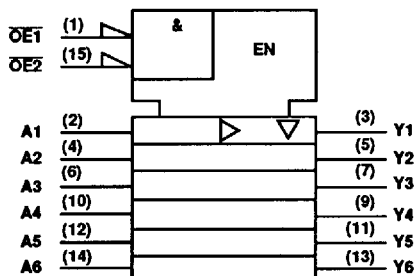
The UT54ACS365 and UT54ACTS365 are non-inverting hex buffer and line driver with three-state outputs. The output enables ($\overline{OE1}$ and $\overline{OE2}$) control the three-state outputs. If $\overline{OE1}$ or $\overline{OE2}$ is high, the outputs will be in a high impedance state. For data, both $\overline{OE1}$ and $\overline{OE2}$ must be low.

The devices are characterized over full military temperature range of -55°C to +125°C.

FUNCTION TABLE

INPUTS			OUTPUT
$\overline{OE1}$	$\overline{OE2}$	A	Y
L	L	L	L
L	L	H	H
X	H	X	Z
H	X	X	Z

LOGIC SYMBOL

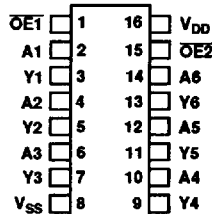


Note:

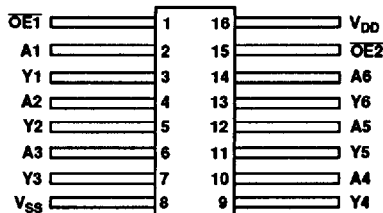
1. This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

PINOUTS

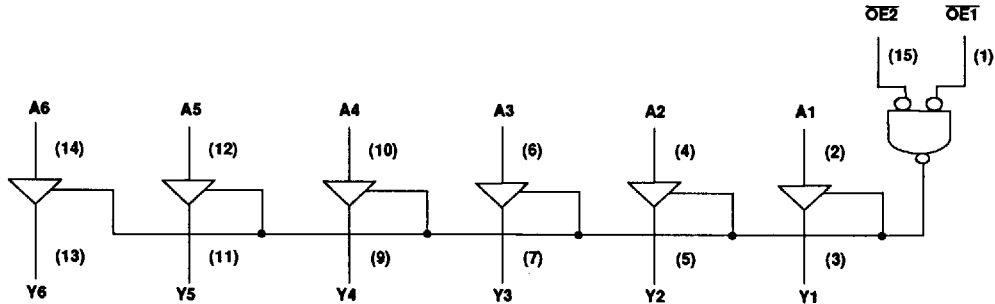
16-Pin DIP Top View



16-Lead Flatpack Top View



LOGIC DIAGRAM

RADIATION HARDNESS SPECIFICATIONS¹

PARAMETER	LIMIT	UNITS
Total Dose	1.0E6	rads(Si)
SEU & SEL Threshold ²	80	MeV-cm ² /mg
Neutron Fluence	1.0E14	n/cm ²

Notes:

- Logic will not latchup during radiation exposure within the limits defined in the table.
- Device storage elements are immune to SEU affects.

ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	LIMIT	UNITS
V _{DD}	Supply voltage	-0.3 to 7.0	V
V _{IO}	Voltage any pin	-.3 to V _{DD} +.3	V
T _{STG}	Storage Temperature range	-65 to +150	°C
T _J	Maximum junction temperature	+175	°C
T _{LS}	Lead temperature (soldering 5 seconds)	+300	°C
Θ _{JC}	Thermal resistance junction to case	20	°C/W
I _I	DC input current	±10	mA
P _D	Maximum power dissipation	1	W

Note:

- Stresses outside the listed absolute maximum ratings may cause permanent damage to the device. This is a stress rating only, functional operation of the device at these or any other conditions beyond limits indicated in the operational sections is not recommended. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIMIT	UNITS
V _{DD}	Supply voltage	4.5 to 5.5	V
V _{IN}	Input voltage any pin	0 to V _{DD}	V
T _C	Temperature range	-55 to + 125	°C

DC ELECTRICAL CHARACTERISTICS ⁷(V_{DD} = 5.0V ±10%; V_{SS} = 0V ⁶, -55°C < T_C < +125°C)

SYMBOL	PARAMETER	CONDITION	MIN	MAX	UNIT
V _{IL}	Low-level input voltage ¹ ACTS ACS			0.8 .3V _{DD}	V
V _{IH}	High-level input voltage ¹ ACTS ACS		.5V _{DD} .7V _{DD}		V
I _{IN}	Input leakage current ACTS/ACS	V _{IN} = V _{DD} or V _{SS}	-1	1	μA
V _{OL}	Low-level output voltage ³ ACTS ACS	I _{OL} = 12.0mA I _{OL} = 100μA		0.40 0.25	V
V _{OH}	High-level output voltage ³ ACTS ACS	I _{OH} = -12.0mA I _{OH} = -100μA	.7V _{DD} V _{DD} - 0.25		V
I _{OZ}	Three-state output leakage current	V _O = V _{DD} and V _{SS}	-20	20	μA
I _{OS}	Short-circuit output current ^{2,4} ACTS/ACS	V _O = V _{DD} and V _{SS}	-200	200	mA
P _{total}	Power dissipation ^{8,9}	C _L = 50pF		1.8	mW/ MHz
I _{DDQ}	Quiescent Supply Current	V _{DD} = 5.5V		10	μA
C _{IN}	Input capacitance ⁵	f = 1MHz @ 0V		15	pF
C _{OUT}	Output capacitance ⁵	f = 1MHz @ 0V		15	pF

Notes:

- Functional tests are conducted in accordance with MIL-STD-883 with the following input test conditions: V_{IH} = V_{IH}(min) + 20%, -0%; V_{IL} = V_{IL}(max) + 0%, -50%, as specified herein, for TTL, CMOS, or Schmitt compatible inputs. Devices may be tested using any input voltage within the above specified range, but are guaranteed to V_{IH}(min) and V_{IL}(max).
- Supplied as a design limit but not guaranteed or tested.
- Per MIL-M-38510, for current density ≤ 5.0E5 amps/cm², the maximum product of load capacitance (per output buffer) times frequency should not exceed 3,765 pF MHz.
- Not more than one output may be shorted at a time for maximum duration of one second.
- Capacitance measured for initial qualification and when design changes may affect the value. Capacitance is measured between the designated terminal and V_{SS} at frequency of 1MHz and a signal amplitude of 50mV rms maximum.
- Maximum allowable relative shift equals 50mV.
- All specifications valid for radiation dose ≤ 1E6 rads(Si).
- Power does not include power contribution of any TTL output sink current.
- Power dissipation specified per switching output.

AC ELECTRICAL CHARACTERISTICS ²(V_{DD} = 5.0V ±10%; V_{SS} = 0V ¹, -55°C < T_C < +125°C)

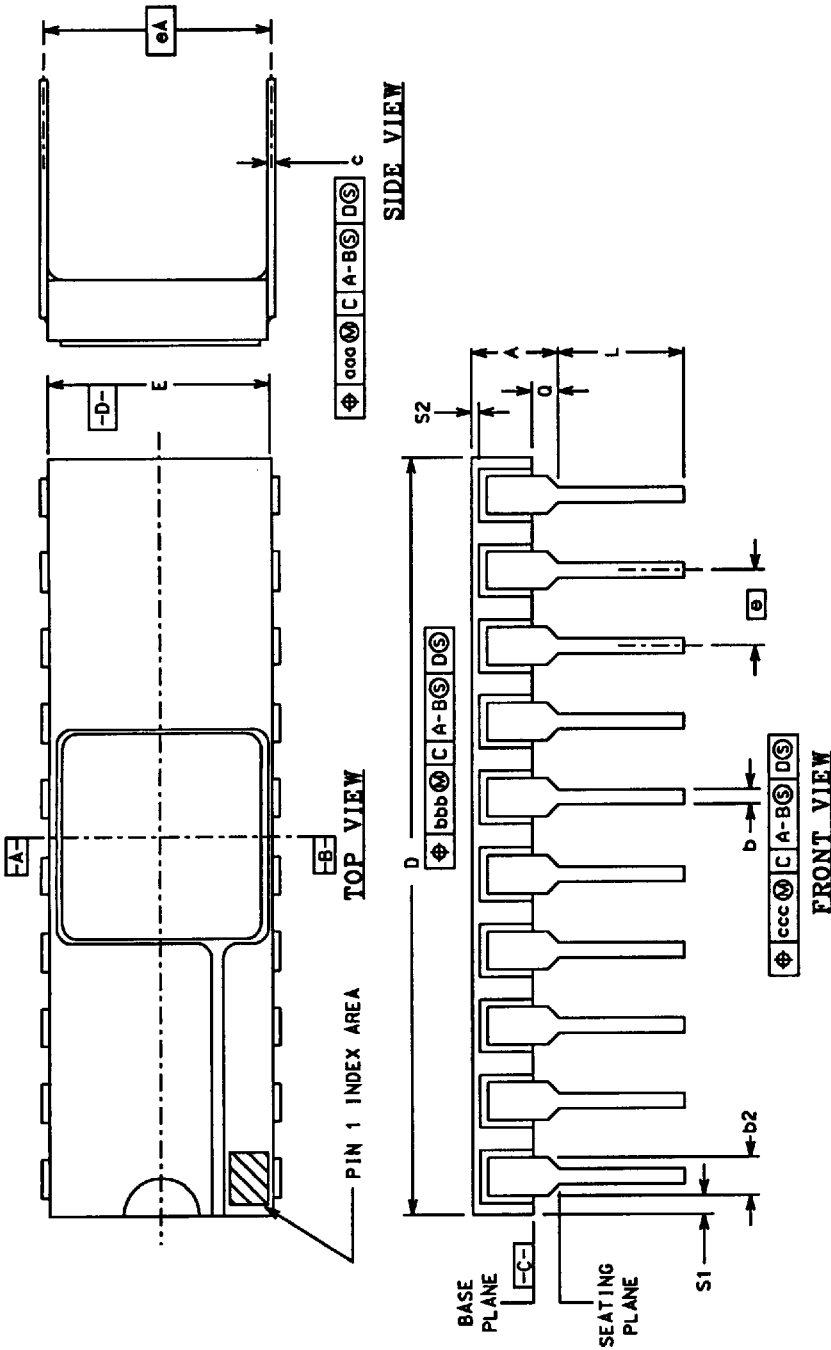
SYMBOL	PARAMETER	MINIMUM	MAXIMUM	UNIT
t _{PLH}	Data to output	2	11	ns
t _{PHL}	Data to output	2	13	ns
t _{PZL}	$\overline{\text{OE}}$ low to output active	2	14	ns
t _{PZH}	$\overline{\text{OE}}$ low to output active	2	15	ns
t _{PLZ}	$\overline{\text{OE}}$ high to output three-state	2	12	ns
t _{PHZ}	$\overline{\text{OE}}$ high to output three-state	2	14	ns

Notes:

1. Maximum allowable relative shift equals 50mV.
2. All specifications valid for radiation dose ≤ 1E6 rads(Si).

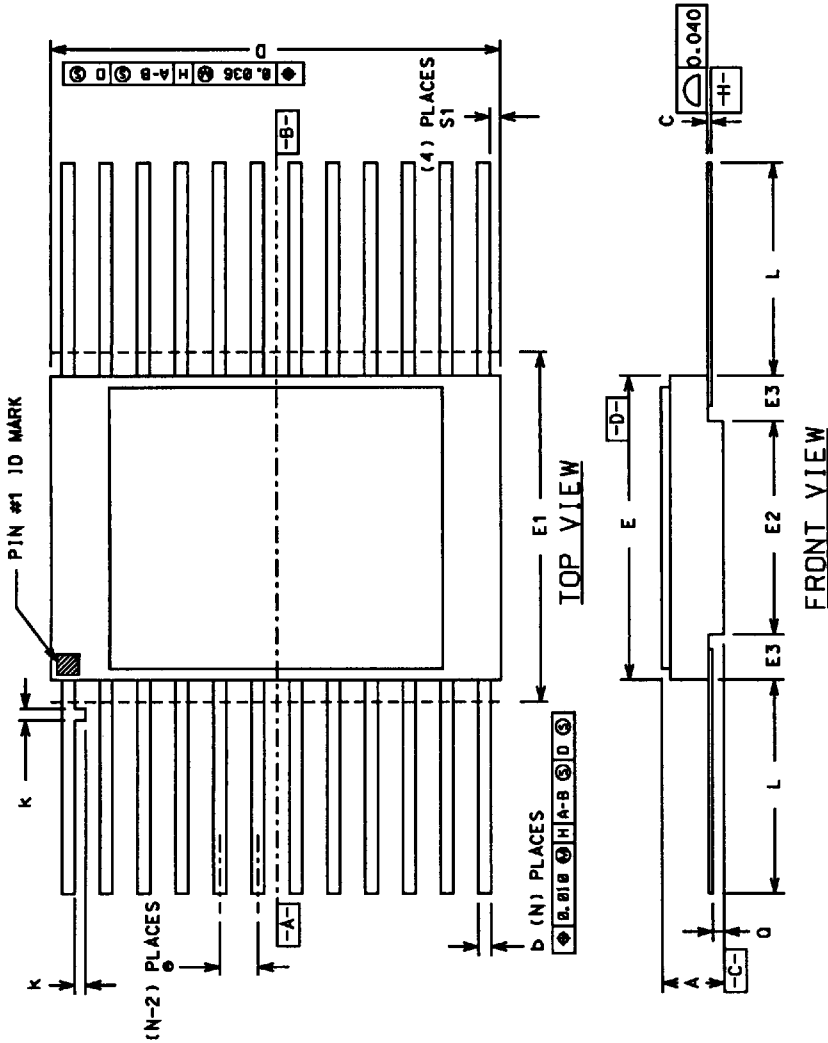
2.0 RAD-HARD MSI PACKAGES

Side-Brazed Packages



PKG CONF 16	LEAD COUNT	MIL-SID- 1835 DWG CONF C	DIMENSION SYMBOLS														
			A	D	b2	C	D	E	e	eA	L	Q	S1	S2	000	00b	00c
-01	14	D-1	0.200	0.026	0.065	0.018	0.785	0.310	0.100	0.300	0.200	0.060	0.005	0.005	0.015	0.030	0.010
			0.014	0.045	0.008	0.840	0.220	BSC	BSC	0.125	0.015	0.005	0.005	0.015	0.030	0.010	
-02	16	D-2	0.200	0.026	0.065	0.018	0.840	0.310	0.100	0.300	0.200	0.060	0.005	0.005	0.015	0.030	0.010
			0.014	0.045	0.008	0.840	0.220	BSC	BSC	0.125	0.015	0.005	0.005	0.015	0.030	0.010	
-03	20	D-8	0.200	0.026	0.065	0.018	1.060	0.310	0.100	0.300	0.200	0.070	0.005	0.005	0.015	0.030	0.010
			0.014	0.045	0.008	1.060	0.220	BSC	BSC	0.125	0.015	0.005	0.005	0.015	0.030	0.010	

Flatpack Packages



PKG CONF IG	LEAD COUNT	MIL-STD 1836 DWG CONF B	DIMENSION SYMBOLS												
			A	b	c	D	E	E1	E2	E3	e	k	L	O	S1
-03	14	F-2A	0.115	0.022	0.009	0.390	0.260	0.290	---	---	---	0.050	0.015	0.370	0.045
			0.045	0.015	0.004	0.235	0.235	0.130	0.030	BSC	0.008	0.270	0.026	0.005	
-04	16	F-5A	0.115	0.022	0.009	0.440	0.285	0.315	---	---	---	0.050	0.015	0.370	0.045
			0.045	0.015	0.004	0.245	0.245	0.130	0.030	BSC	0.008	0.250	0.026	0.005	
-05	20	F-9A	0.115	0.022	0.009	0.540	0.300	0.330	---	---	---	0.050	0.015	0.370	0.045
			0.045	0.015	0.004	0.245	0.245	0.130	0.030	BSC	0.008	0.250	0.026	0.000	